

### NOT RECOMMENDED FOR NEW DESIGN **USE DMN3110S**



Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

Terminals: Finish - Matte Tin Annealed Over Copper

Leadframe. Solderable per MIL-STD-202, Method 208 (3)

Moisture Sensitivity: Level 1 per J-STD-020

Terminal Connections: See Diagram

Weight: 0.008 grams (Approximate)

**Mechanical Data** 

Package: SOT23

**DMN3112S** 

#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Features**

- Low On-Resistance:
  - $57m\Omega$  @ VGS = 10V
  - $112m\Omega$  @ VGS = 4.5V
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed

products/.

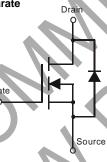
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at https://www.diodes.com/products/automotive/automotive-
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

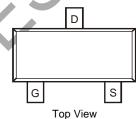
https://www.diodes.com/quality/product-definitions/

An Automotive-Compliant Part is Available Under Separate Datasheet (DMN3112SQ)

SOT23

Top View





**Equivalent Circuit** 

Pin Configuration

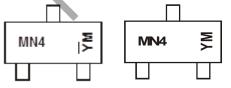
## Ordering Information (Note 4)

Part Number	Qualification	Packago	Packing	
Fait Nulliber	Qualification	Package	Qty.	Carrier
DMN3112S-7	Standard	SOT23	3000pcs	Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



MN4 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test Site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test Site) Y or  $\overline{Y}$  = Year (ex: I = 2021)

M = Month (ex: 9 = September)

Chengdu A/T Site

Shanghai A/T Site

Date Code Key

Year	2007		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	U		-	J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain Source Voltage	$V_{DSS}$	30	V	
Gate-Source Voltage		Vgss	±20	V
Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	lo	5.8 4.2	А
Drain Current (Note 5)	I <sub>DM</sub>	20	A	
Body-Diode Continuous Current (Note 5)		ls	2.0	Α

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient @TA = +25°C (Note 5)	RθJA	90	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

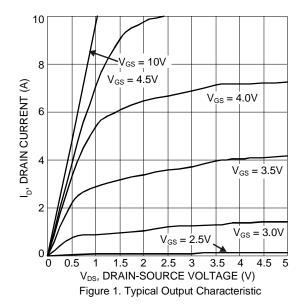
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

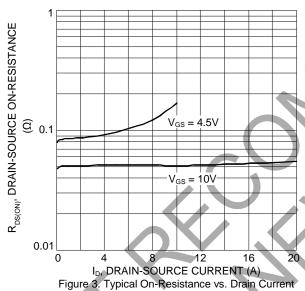
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BVDSS	30	<b>\_/</b>		V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS		X	800	nA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	
Gate-Body Leakage	IGSS	-	7	±80 ±800	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	Vgs(TH)	1.3	1.9	2.2	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	1	47 92	57 112	mΩ	V <sub>G</sub> S = 10V, I <sub>D</sub> = 5.8A V <sub>G</sub> S = 4.5V, I <sub>D</sub> = 4.2A	
Forward Transconductance	Y <sub>fs</sub>	_	4.7	_	S	V <sub>DS</sub> = 5V, I <sub>D</sub> = 4.2A	
Source-Drain Diode Forward Voltage	V <sub>SD</sub>	_	0.78	1.1	V	Vgs = 0V, Is = 2.0A	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	268	_	pF	., -,,,,	
Output Capacitance		_	73	_	pF	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0V - f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	50	_	pF	71 = 1.01VII 12	

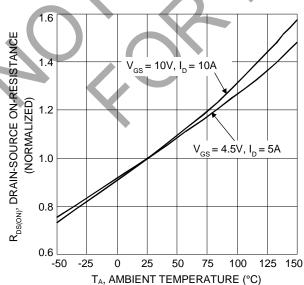
Notes:

- 5. Device mounted on FR-4 PCB. t ≤ 5 sec.
  6. Short duration pulse test used to minimize self-heating effect.
  7. Guaranteed by design. Not subject to production festing.



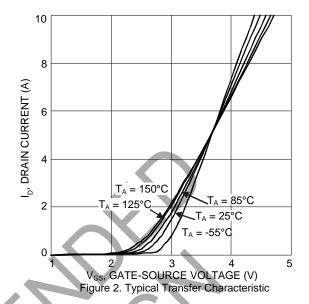






and Gate Voltage

Figure 5. On-Resistance Variation with Temperature



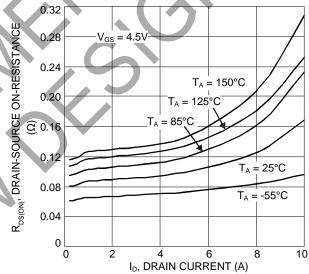


Figure 4. Typical On-Resistance vs. Drain Current and Temperature

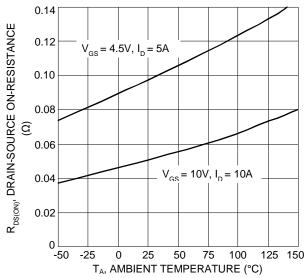


Figure 6. On-Resistance Variation with Temperature



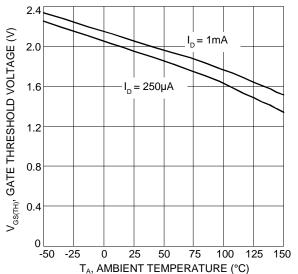
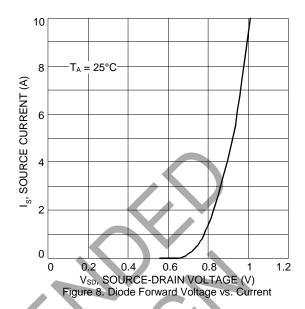
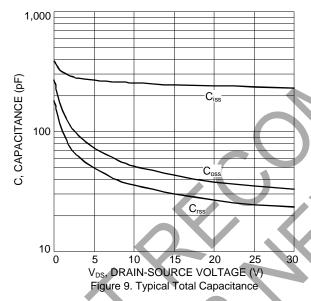


Figure 7. Gate Threshold Variation vs. Ambient Temperature





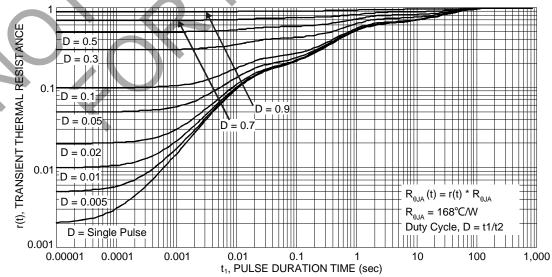


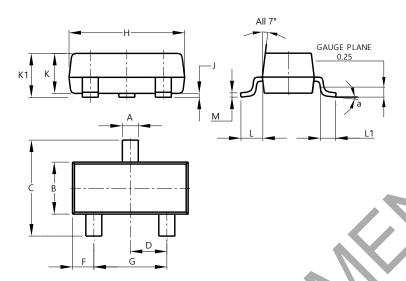
Figure 10. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

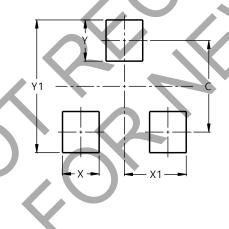


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
Ú	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Ŧ	2.80	3.00	2.90			
5	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
٦	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
M	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	29



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